

**Silizium-Differential-Fotodiode**  
**Silicon Differential Photodiode**  
**Lead (Pb) Free Product - RoHS Compliant**

**BPX 48**



**Wesentliche Merkmale**

- Speziell geeignet für Anwendungen im Bereich von 400 nm bis 1100 nm
- Hohe Fotoempfindlichkeit
- DIL-Plastikbauform mit hoher Packungsdichte
- Doppeldiode mit extrem hoher Gleichmäßigkeit

**Features**

- Especially suitable for applications from 400 nm to 1100 nm
- High photosensitivity
- DIL plastic package with high packing density
- Double diode with extremely high homogeneousness

**Anwendungen**

- Nachlaufsteuerung
- Kantenführungen
- Weg- bzw. Winkelabtastungen
- Industrieelektronik
- „Messen/Steuern/Regeln“

**Application**

- Follow-up control
- Edge control
- Path and angle scanning
- Industrial electronics
- For control and drive circuits

Typ Type	Bestellnummer Ordering Code
BPX 48	Q62702P0017S0001

**Grenzwerte**  
**Maximum Ratings**

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Betriebs- und Lagertemperatur Operating and storage temperature range	$T_{\text{op}}; T_{\text{stg}}$	- 40 ... + 80	°C
Sperrspannung Reverse voltage	$V_R$	10	V
Verlustleistung, $T_A = 25$ °C Total power dissipation	$P_{\text{tot}}$	50	mW

**Kennwerte ( $T_A = 25$  °C)** für jede Einzeldiode

**Characteristics ( $T_A = 25$  °C)** per single diode system

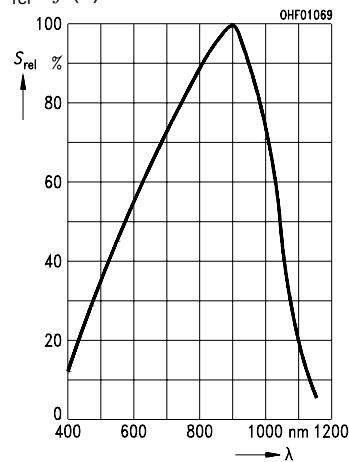
Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Fotostrom Photocurrent $V_R = 5$ V, Normlicht/standard light A, $T = 2856$ K, $E_V = 1000$ lx	$I_P$	24 ( $\geq 15$ )	μA
Wellenlänge der max. Fotoempfindlichkeit Wavelength of max. sensitivity	$\lambda_{S \text{ max}}$	900	nm
Spektraler Bereich der Fotoempfindlichkeit $S = 10\%$ von $S_{\text{max}}$ Spectral range of sensitivity $S = 10\%$ of $S_{\text{max}}$	$\lambda$	400 ... 1150	nm
Bestrahlungsempfindliche Fläche Radiant sensitive area	$A$	1.54	mm <sup>2</sup>
Abmessung der bestrahlungsempfindlichen Fläche Dimensions of radiant sensitive area	$L \times B$ $L \times W$	0.7 × 2.2	mm × mm
Halbwinkel Half angle	$\varphi$	± 60	Grad deg.
Dunkelstrom, $V_R = 10$ V Dark current	$I_D$	10 ( $\leq 100$ )	nA
Spektrale Fotoempfindlichkeit Spectral sensitivity $\lambda = 850$ nm	$S_\lambda$	0.55	A/W

**Kennwerte ( $T_A = 25^\circ\text{C}$ ) für jede Einzeldiode**

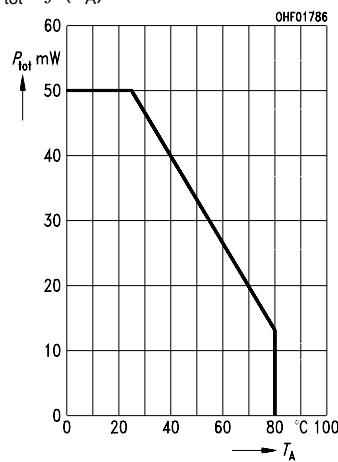
**Characteristics ( $T_A = 25^\circ\text{C}$ ) per single diode system (cont'd)**

Bezeichnung Parameter	Symbol Symbol	Wert Value	Einheit Unit
Max. Abweichung der Fotoempfindlichkeit der Systeme vom Mittelwert Max. deviation of the system spectral sensitivity from the average	$\Delta S$	$\pm 5$	%
Quantenausbeute Quantum yield $\lambda = 850 \text{ nm}$	$\eta$	0.8	Electrons Photon
Leerlaufspannung Open-circuit voltage $E_v = 1000 \text{ lx, Normlicht/standard light A, } T = 2856 \text{ K}$	$V_O$	330 ( $\geq 280$ )	mV
Kurzschlussstrom Short-circuit current $E_v = 1000 \text{ lx, Normlicht/standard light A, } T = 2856 \text{ K}$	$I_{SC}$	24	$\mu\text{A}$
Anstiegs- und Abfallzeit des Fotostromes Rise and fall time of the photocurrent $R_L = 1 \text{ k}\Omega; V_R = 5 \text{ V; } \lambda = 850 \text{ nm; } I_p = 20 \text{ }\mu\text{A}$	$t_r, t_f$	500	ns
Durchlassspannung, $I_F = 40 \text{ mA, } E = 0$ Forward voltage	$V_F$	1.3	V
Kapazität, $V_R = 0 \text{ V, } f = 1 \text{ MHz, } E = 0$ Capacitance	$C_0$	25	pF
Temperaturkoeffizient von $V_O$ Temperature coefficient of $V_O$	$TC_V$	-2.6	mV/K
Temperaturkoeffizient von $I_{SC}$ Temperature coefficient of $I_{SC}$ Normlicht/standard light A	$TC_I$	0.18	%/K
Rauschäquivalente Strahlungsleistung Noise equivalent power $V_R = 10 \text{ V, } \lambda = 950 \text{ nm}$	$NEP$	$1.0 \times 10^{-13}$	$\frac{\text{W}}{\sqrt{\text{Hz}}}$
Nachweisgrenze, $V_R = 10 \text{ V, } \lambda = 950 \text{ nm}$ Detection limit	$D^*$	$1.2 \times 10^{12}$	$\frac{\text{cm} \times \sqrt{\text{Hz}}}{\text{W}}$

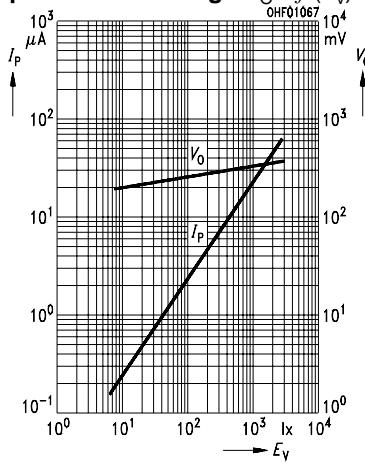
**Relative Spectral Sensitivity**  
 $S_{\text{rel}} = f(\lambda)$



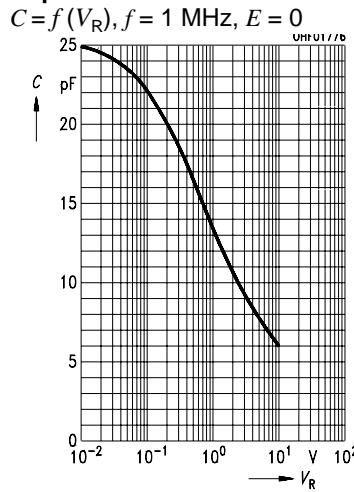
**Total Power Dissipation**  
 $P_{\text{tot}} = f(T_A)$



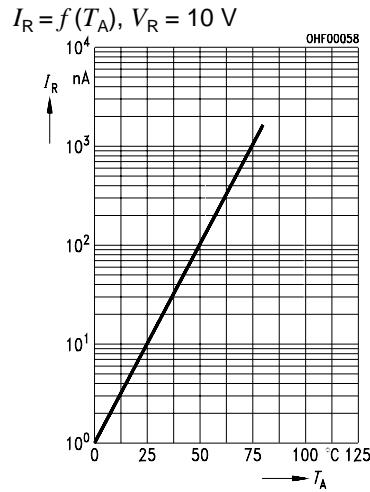
**Photocurrent  $I_P = f(E_v)$ ,  $V_R = 5 \text{ V}$**   
**Open-Circuit Voltage  $V_O = f(E_v)$**



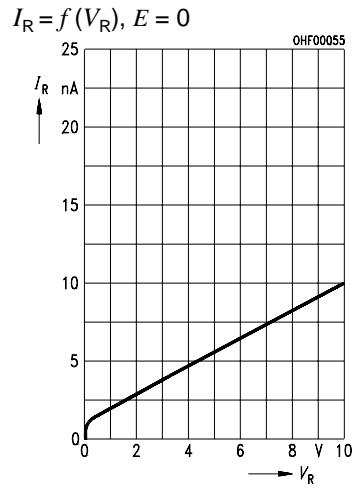
**Capacitance**



**Dark Current**

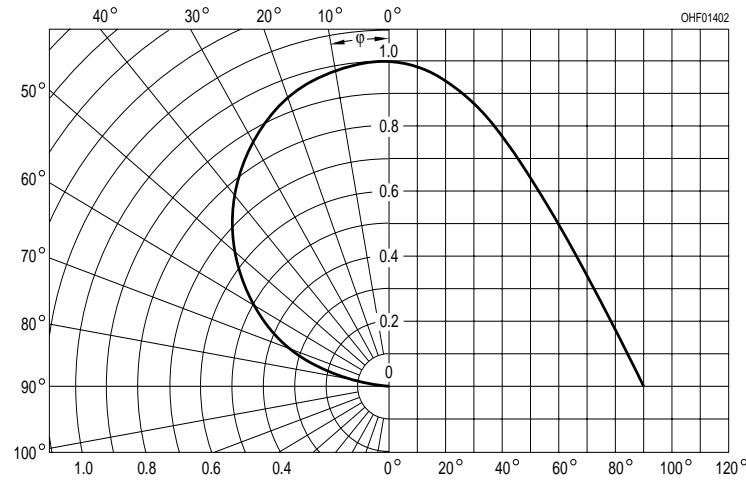


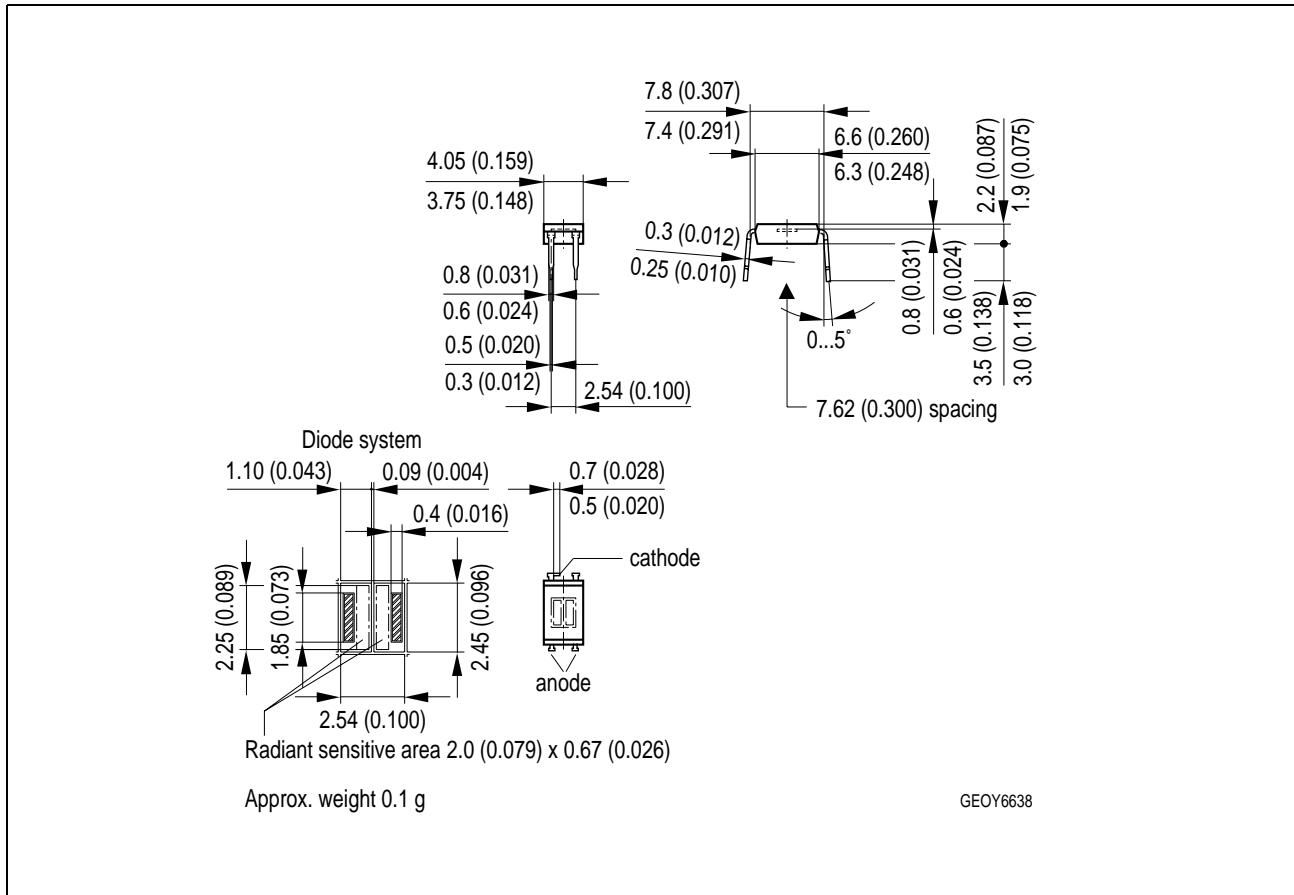
**Dark Current**



**Directional Characteristics**

$$S_{\text{rel}} = f(\varphi)$$

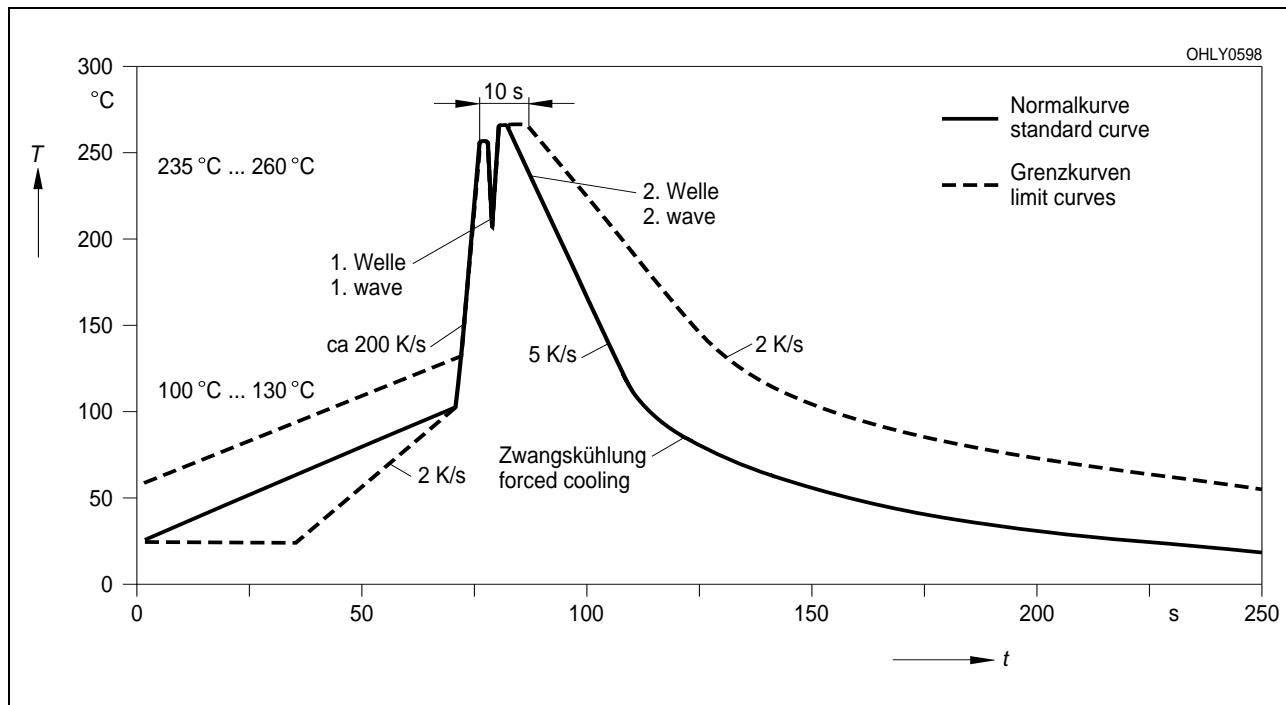


**Maßzeichnung  
Package Outlines**

Maße in mm (inch) / Dimensions in mm (inch).

**Lötbedingungen**  
**Soldering Conditions**  
**Wellenlöten (TTW)**  
**TTW Soldering**

(nach CECC 00802)  
 (acc. to CECC 00802)



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EU RoHS and China RoHS compliant product



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